SIEMENS

Data sheet 3RF2130-1AA45



Semiconductor relay, 1-phase 3RF2 Overall width 22.5 mm, 30 A 48-600 V / 4-30 V DC screw terminal Blocking voltage 1200 V

product brand name	SIRIUS
product designation	solid-state relay
design of the product	single-phase
product type designation	3RF21
manufacturer's article number	
_1 of the accessories that can be ordered	3RF2900-3PA88
_2 of the accessories that can be ordered	3RF2950-0HA16
_3 of the accessories that can be ordered	3RF2900-0EA18
_4 of the accessories that can be ordered	3RF2950-0GA16
_5 of the accessories that can be ordered	3RF2920-0FA08
product designation	
_1 of the accessories that can be ordered	terminal cover
_2 of the accessories that can be ordered	power regulator
_3 of the accessories that can be ordered	converter
_4 of the accessories that can be ordered	load monitoring
_5 of the accessories that can be ordered	load monitoring, basis
General technical data	
product function	zero-point switching
power loss [V·A] maximum	44.2 VA
power loss [W] for rated value of the current	
 at AC in hot operating state 	44.2 W
 at AC in hot operating state per pole 	44.2 W
 without load current share typical 	0.5 W
insulation voltage rated value	600 V
type of voltage	
 of the operating voltage 	AC
of the control supply voltage	DC
surge voltage resistance of main circuit rated value	6 kV
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to DIN 40719 extended according to IEC 204-2 according to IEC 750	K
reference code according to EN 61346-2	Q
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	05/28/2009
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0

time of voltage of the annual transition will be	AC
type of voltage of the operating voltage	AC
operating voltage	
• at AC	
— at 50 Hz rated value	48 600 V
— at 60 Hz rated value	48 600 V
operating frequency rated value	50 60 Hz
relative symmetrical tolerance of the operating frequency	10 %
operating range relative to the operating voltage at AC	
● at 50 Hz	40 660 V
• at 60 Hz	40 660 V
operational current	
at AC-51 rated value	30 A
according to UL 508 rated value	30 A
ampacity maximum	30 A
operational current minimum	500 mA
rate of voltage rise at the thyristor for main contacts maximum permissible	500 V/μs
blocking voltage at the thyristor for main contacts maximum permissible	1 200 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	300 A
I2t value maximum	450 A²·s
Control circuit/ Control	
type of voltage of the control supply voltage	DC
control supply voltage 1 at DC	
rated value maximum permissible	30 V
•	4 30 V
control supply voltage	
at DC initial value for signal <1> detection	4 V
at DC full-scale value for signal<0> recognition	1 V
control current at minimum control supply voltage	
• at DC	13 mA
control current at DC rated value	15 mA
ON-delay time	1 ms; additionally max. one half-wave
OFF-delay time	1 ms; additionally max. one half-wave
Auxiliary circuit	
number of NC contacts for auxiliary contacts	0
number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method side-by-side mounting	Yes
fastening method	screw fixing
design of the thread of the screw for securing the equipment	M4
tightening torque of fixing screw maximum	1.5 N·m
tightening torque [lbf·in] of fixing screw maximum	13 lbf·in
height	85 mm
width	22.5 mm
depth	48 mm
Connections/ Terminals	
product component removable terminal for auxiliary and	Yes
type of electrical connection	
type of electrical connection	scraw-tyng terminals
for main current circuit for auxiliary and control circuit	screw-type terminals
for auxiliary and control circuit type of connectable conductor cross-sections	screw-type terminals
type of connectable conductor cross-sections	
for main contacts — solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
- soliu	
— finely stranded with core and processing	2x (1 2.5 mm²) 2x (2.5 6 mm²) 1x 10 mm²
 finely stranded with core end processing for AWG cables for main contacts 	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm² 2x (14 10)
— finely stranded with core end processing • for AWG cables for main contacts connectable conductor cross-section for main contacts	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm² 2x (14 10)

 solid or stranded 	1 F G mm ²
a finally atranded with some and processing	1.5 6 mm ²
finely stranded with core end processing type of connectable conductor cross sections	1 10 mm²
type of connectable conductor cross-sections	
 for auxiliary and control contacts — solid 	1v (0.5 2.5 mm²) 2v (0.5 1.0 mm²)
	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²) 1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded with core end processing finely stranded without core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
for AWG cables for auxiliary and control contacts	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for	14 10
main contacts	1110
tightening torque	
 for main contacts with screw-type terminals 	2 2.5 N·m
 for auxiliary and control contacts with screw-type terminals 	0.5 0.6 N·m
tightening torque [lbf·in]	
 for main contacts with screw-type terminals 	7 10.3 lbf·in
for auxiliary and control contacts with screw-type terminals	4.5 5.3 lbf·in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	
• for main contacts	7 mm
for auxiliary and control contacts	7 mm
Electrical Safety	IDOO
protection class IP on the front according to IEC 60529	IP20
touch protection on the front according to IEC 60529 Ambient conditions	finger-safe, for vertical contact from the front
installation altitude at height above sea level maximum	1 000 m
ambient temperature	1 000 111
during operation	-25 +60 °C
during operation during storage	-55 +80 °C
Electromagnetic compatibility	30 100 °C
conducted interference	
 due to burst according to IEC 61000-4-4 	
■ uuc to burst according to IEC 01000-4-4	2 kV / 5 kHz behavior criterion 2
 due to burst according to IEC 61000-4-4 due to conductor-earth surge according to IEC 61000-4-5 	2 kV / 5 kHz behavior criterion 2 2 kV behavior criterion 2
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 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 	2 kV behavior criterion 2
 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000- 	2 kV behavior criterion 2 1 kV behavior criterion 2
 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
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Approvals Certificates

General Product Approval

EMV





Confirmation







Test Certificates other Railway Environment

Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Special Test Certificate

Environmental Confirmations

Further information

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2130-1AA45

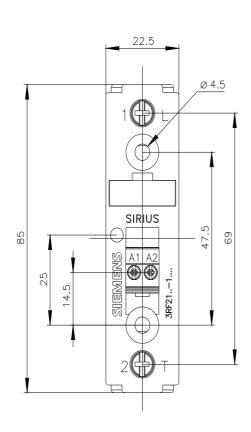
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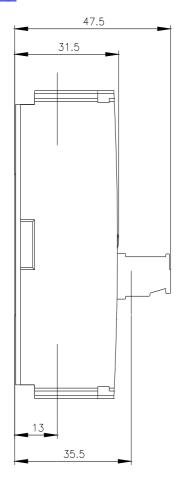
http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3RF2130-1AA45

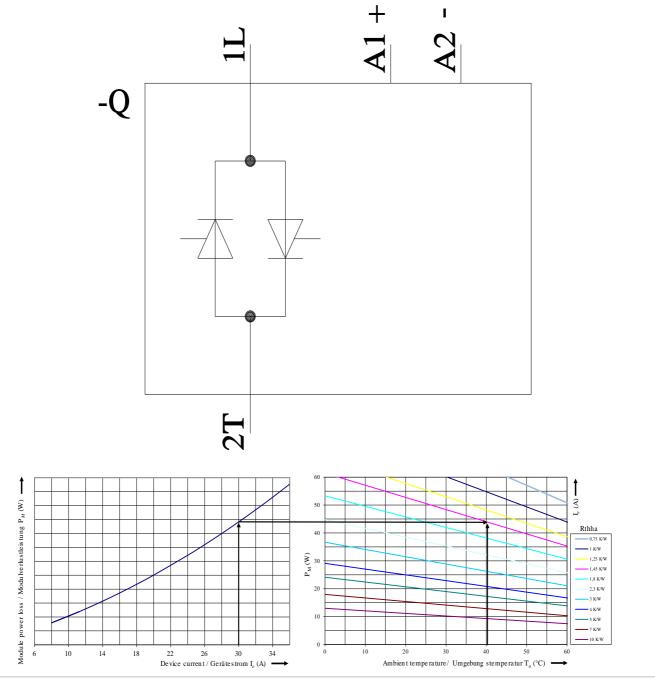
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https://support.industry.siemens.com/cs/ww/en/ps/3RF2130-1AA45

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...) http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3RF2130-1AA45&lang=en







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